

参数(Parameter)	符号(Symbol)	单位(Uint)	测试条件(Condition)			FP202
			Freq.	Fluxden.	Temp.	
初始磁导率 (Initial lPermeability)	$\mu_i$	/	100kHz	100mV	23°C	2000±25%
饱和磁通密度 (Saturation Flux Density)	$B_s$	mT	50Hz	4000A/m	23°C	290
相对损失系数 (Relative loss factor)	$\tan\delta/\mu_i$	$\times 10^{-6}$	100kHz		23°C	20
相对温度系数 (Relative temperature factor)	$\alpha_{\mu ir}$	$\times 10^{-6}$	100kHz		20 ~ 60°C	5
单位体积磁芯损失 (Core loss volume density)	$P_{cv}$	KW/m <sup>3</sup>	50kHz	150mT	23°C	350
居里温度 (Curie Temperature)	$T_c$	°C				100
电阻率 (Electrical Resistivity)	$\rho$	$\Omega \cdot m$				$10^6$
密度 (Density)	$d$	g/cm <sup>3</sup>				5.1

说明以上性能采用  $\varnothing 12.7 \times \varnothing 7.9 \times 2.5$  磁环, 在不加外力的情况下测试, 不同产品在特性表现上略有差异。

Note: Measured on sintered, non-ground ring cores of dimensions  $\varnothing 12.7 \times \varnothing 7.9 \times 2.5$  which are not subjected to external stresses. Product specification will differ from these data due to the influence of geometry and size.

